

CMPSH05-4**SURFACE MOUNT SILICON
HIGH CURRENT, LOW V_F
SCHOTTKY DIODE****SOT-23 CASE**www.centrasemi.com**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMPSH05-4 is a high current, low V_F 40 volt Schottky diode packaged in a space saving SOT-23 surface mount case. This device has been designed for small signal general purpose applications when small size and operational efficiency are prime requirements.

MARKING CODE: C054**FEATURES:**

- Low V_F = 0.35V max @ 100mA
- V_{RRM} = 40V
- I_F = 500mA

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Peak Repetitive Reverse Voltage
 Continuous Forward Current
 Peak Repetitive Forward Current, $t_p \leq 1.0\text{ms}$
 Peak Forward Surge Current, $t_p = 8.0\text{ms}$
 Power Dissipation
 Operating and Storage Junction Temperature
 Thermal Resistance

SYMBOL

V_{RRM} 40
 I_F 500
 I_{FRM} 3.5
 I_{FSM} 10
 P_D 350
 T_J, T_{stg} -65 to +150
 θ_{JA} 357

UNITS

V
 mA
 A
 A
 mW
 $^\circ\text{C}$
 $^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

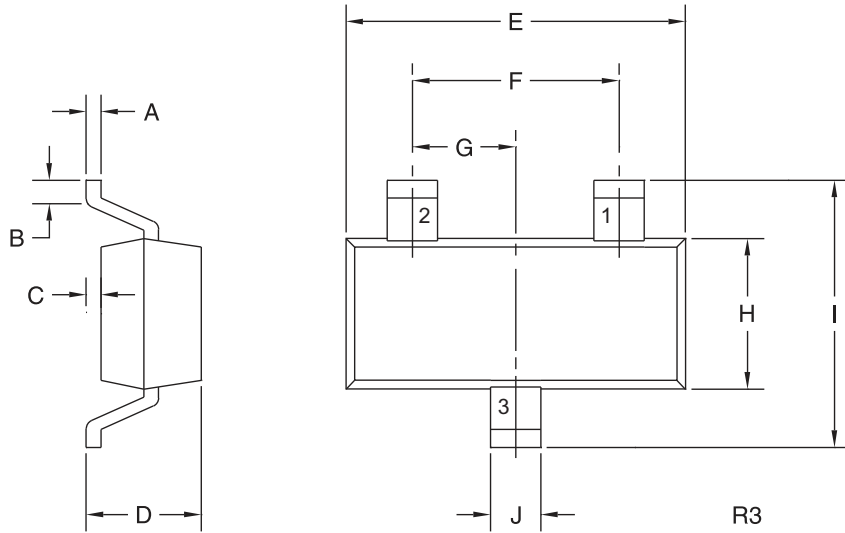
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_R	$V_R=10\text{V}$		30	μA
I_R	$V_R=30\text{V}$		100	μA
BV_R	$I_R=500\mu\text{A}$	40		V
V_F	$I_F=100\mu\text{A}$		0.13	V
V_F	$I_F=1.0\text{mA}$		0.21	V
V_F	$I_F=10\text{mA}$		0.27	V
V_F	$I_F=100\text{mA}$		0.35	V
V_F	$I_F=500\text{mA}$		0.47	V
C_J	$V_R=1.0\text{V}, f=1.0\text{MHz}$		50	pF

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SOT-23 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Anode
- 2) No Connection
- 3) Cathode

MARKING CODE: C054

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.003	0.007	0.08	0.18
B	0.006	-	0.15	-
C	-	0.005	-	0.13
D	0.035	0.043	0.89	1.09
E	0.110	0.120	2.80	3.05
F	0.075		1.90	
G	0.037		0.95	
H	0.047	0.055	1.19	1.40
I	0.083	0.098	2.10	2.49
J	0.014	0.020	0.35	0.50

SOT-23 (REV: R3)

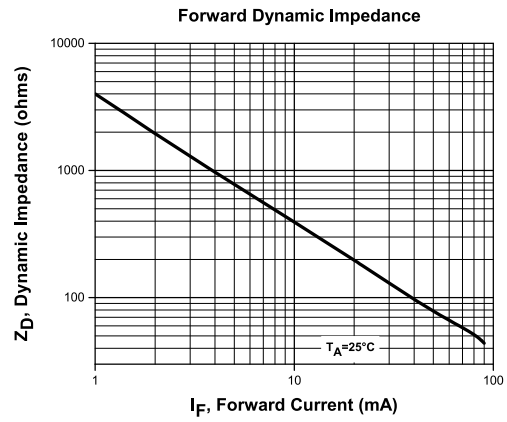
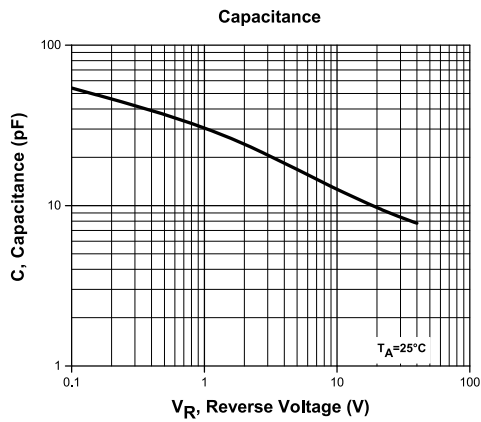
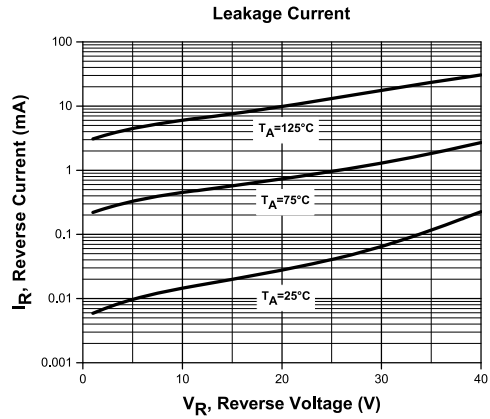
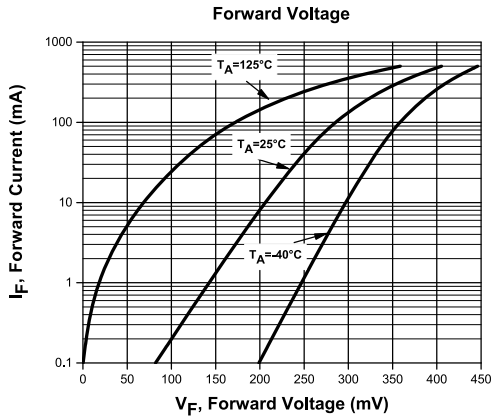
R3 (8-January 2018)

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TYPICAL ELECTRICAL CHARACTERISTICS



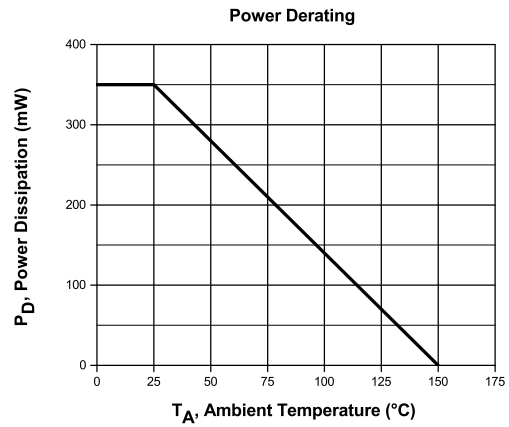
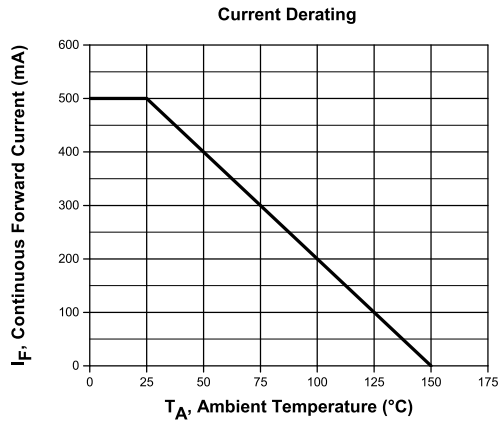
R3 (8-January 2018)

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TYPICAL ELECTRICAL CHARACTERISTICS



R3 (8-January 2018)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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